

N-channel 30 V, 6.5 m Ω logic level MOSFET in LFPAK33 using NextPowerS3 Technology

21 January 2019

Product data sheet

1. General description

Logic level gate drive N-channel enhancement mode MOSFET in an LFPAK33 package. The NextPowerS3 portfolio, utilising Nexperia's unique "SchottkyPlus" technology, delivers high efficiency and the low spiking performance usually associated with MOSFETs with an integrated Schottky or Schottky-like body diode but without problematic high leakage current. NextPowerS3 is particularly suited to high efficiency applications at high switching frequencies.

2. Features and benefits

- Ultra low Q_G, Q_{GD} and Q_{OSS} for high system efficiency, especially at higher switching frequencies
- Superfast switching with soft-recovery; s-factor > 1
- Low spiking and ringing for low EMI designs
- Unique "SchottkyPlus" technology; Schottky-like performance with < 1 μA leakage at 25 °C
- Optimised for 4.5 V gate drive
- Low parasitic inductance and resistance
- High reliability clip bonded and solder die attach Mini Power SO8 package; no glue, no wire bonds, qualified to 175 °C
- Exposed leads for optimal visual solder inspection

3. Applications

- On-board DC-to-DC solutions for server and telecommunications
- Secondary-side synchronous rectification in telecommunication applications
- Voltage regulator modules (VRM)
- Point-of-Load (POL) modules
- Power delivery for V-core, ASIC, DDR, GPU, VGA and system components
- Brushed and brushless motor control

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	-	30	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	-	65	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	-	51	W
Static chara	octeristics	·				
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 15 A; T _j = 25 °C; Fig. 10	-	7	8.6	mΩ
Dynamic ch	aracteristics	•				
Q _{GD}	gate-drain charge	I_D = 15 A; V_{DS} = 15 V; V_{GS} = 4.5 V; Fig. 12; Fig. 13	-	1.7	3	nC

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5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	S	source		D			
2	S	source					
3	S	source		G-(F			
4	G	gate		mbb076 S			
mb	D	mounting base; connected to drain	LFPAK33 (SOT1210)				

6. Ordering information

Table 3. Ordering information							
Type number	Package	ackage					
	Name	Description	Version				
PSMN6R5-30MLD	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 8 leads	SOT1210				

7. Marking

Table 4. Marking codes					
	Type number	Marking code			
	PSMN6R5-30MLD	6D530L			

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C	-	30	V
V _{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ	-	30	V
V _{GS}	gate-source voltage		-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>	-	51	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	-	65	A
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>	-	46	A
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3	-	262	A
T _{stg}	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
T _{sld(M)}	peak soldering temperature		-	260	°C
Source-drain	n diode				
I _S	source current	T _{mb} = 25 °C	-	42	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$	-	262	A
Avalanche r	uggedness				

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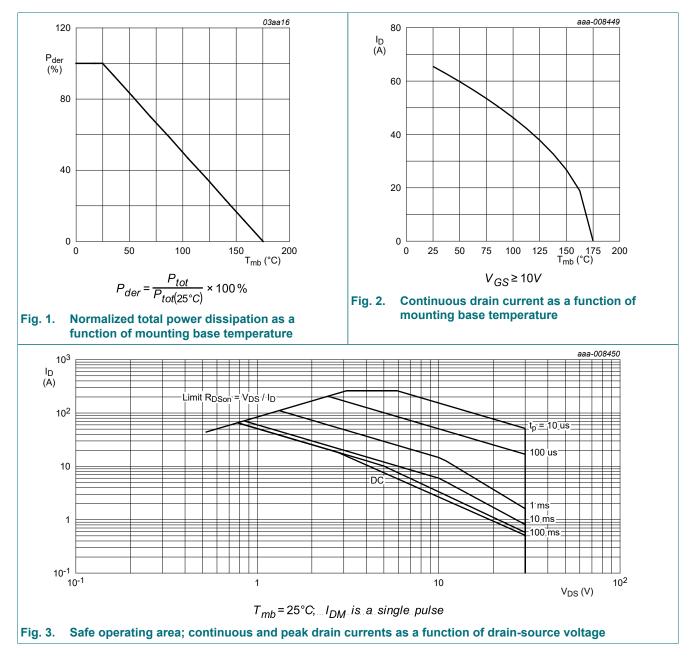
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Symbol	Parameter	Conditions		Min	Мах	Unit
DO(AL)O		$ \begin{split} &I_D = 15 \text{ A}; V_{sup} \leq \ 30 \text{ V}; R_{GS} = 50 \ \Omega; \\ &V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \ ^\circ\text{C}; unclamped; \\ &t_p = 146 \ \mu\text{s} \end{split} $	[1]	-	42.7	mJ

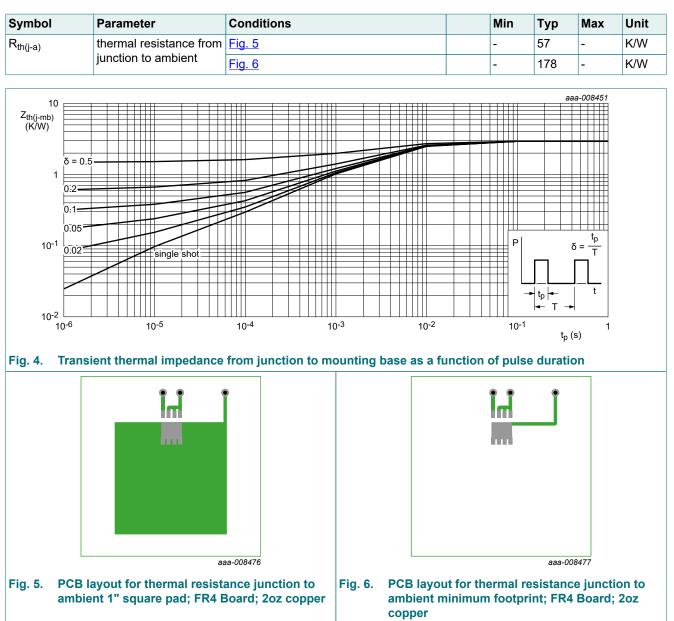
[1] Protected by 100% test



9. Thermal characteristics

Cable 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 4</u>		-	2.72	2.94	K/W

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10. Characteristics

Table 7. Char		- ···				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V
	breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C	27	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} =V _{GS} ; T _j = 25 °C	1.2	1.68	2.2	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-3.9	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 24 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{DS} = 24 V; V _{GS} = 0 V; T _j = 125 °C	-	0.42	-	μA
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA

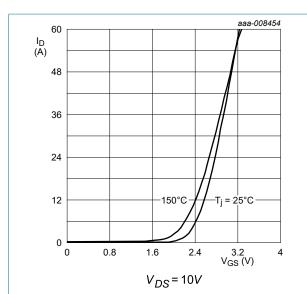
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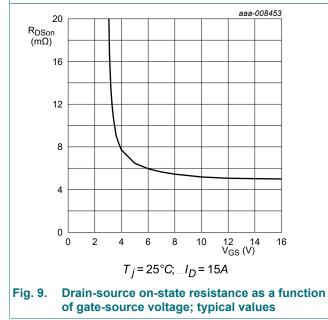
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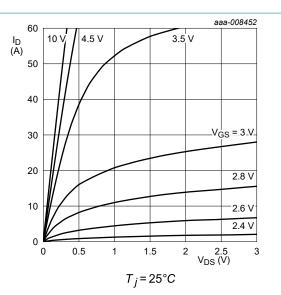
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C		-	-	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 15 A; T _j = 25 °C; Fig. 10		-	7	8.6	mΩ
		V _{GS} = 4.5 V; I _D = 15 A; T _j = 150 °C; <u>Fig. 10; Fig. 11</u>		-	-	14.2	mΩ
		V _{GS} = 10 V; I _D = 15 A; T _j = 25 °C; <u>Fig. 10</u>		-	5.5	6.5	mΩ
	V _{GS} = 10 V; I _D = 15 A; T _j = 150 °C; <u>Fig. 10</u> ; <u>Fig. 11</u>		-	-	10.7	mΩ	
R _G	gate resistance	f = 1 MHz		-	0.44	1.5	Ω
Dynamic ch	aracteristics						
Q _{G(tot)}	total gate charge	I _D = 15 A; V _{DS} = 15 V; V _{GS} = 10 V; Fig. 12; Fig. 13		-	13.6	20	nC
		I _D = 15 A; V _{DS} = 15 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13		-	6.4	10	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}$		-	12.7	-	nC
Q _{GS}	gate-source charge	I _D = 15 A; V _{DS} = 15 V; V _{GS} = 4.5 V;		-	1.5	4	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13		-	1.3	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge			-	0.2	-	nC
Q _{GD}	gate-drain charge	_		-	1.7	3	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 15 A; V _{DS} = 15 V; <u>Fig. 12</u> ; <u>Fig. 13</u>		-	2	-	V
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz;		-	817	-	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		-	605	-	pF
C _{rss}	reverse transfer capacitance	_		-	62	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 15 V; R _L = 1 Ω; V _{GS} = 4.5 V;		-	7.5	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	11	-	ns
t _{d(off)}	turn-off delay time			-	9.8	-	ns
t _f	fall time			-	7.2	-	ns
Q _{oss}	output charge	V _{GS} = 0 V; V _{DS} = 15 V; f = 1 MHz; T _j = 25 °C		-	12.3	-	nC
Source-drai	n diode						
V _{SD}	source-drain voltage	I_{S} = 10 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 15</u>		-	0.81	1.2	V
t _{rr}	reverse recovery time	$I_{S} = 15 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{V}_{GS} = 0 \text{ V};$		-	23.8	-	ns
Q _r	recovered charge		[1]	-	12.6	-	nC
t _a	reverse recovery rise time			-	10.3	-	ns
t _b	reverse recovery fall time			-	13.5	-	ns
S	softness factor			-	1.3	-	

[1] includes capacitive recovery

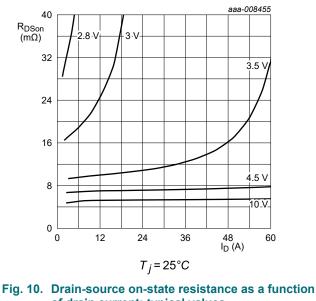






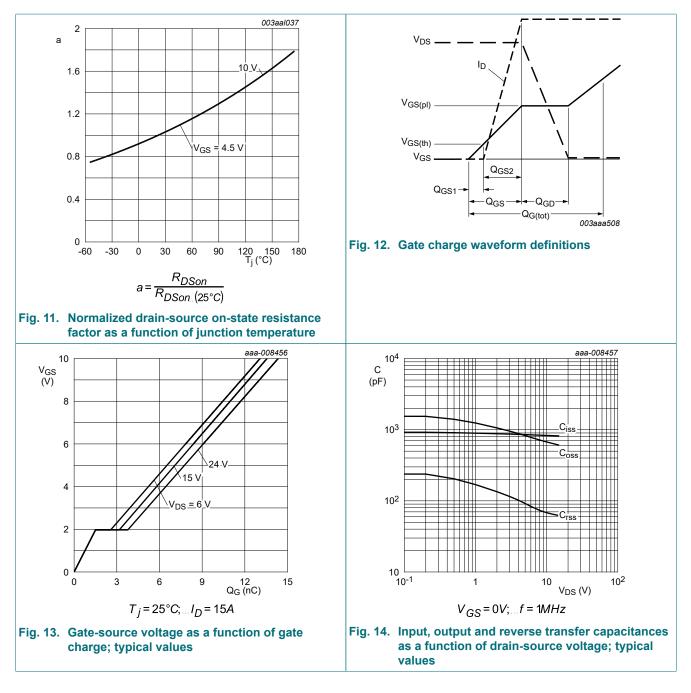




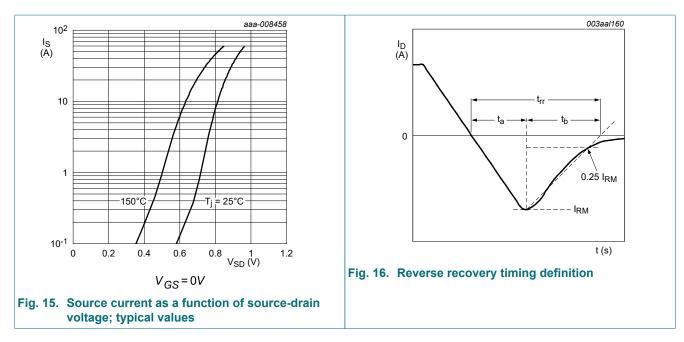


of drain current; typical values

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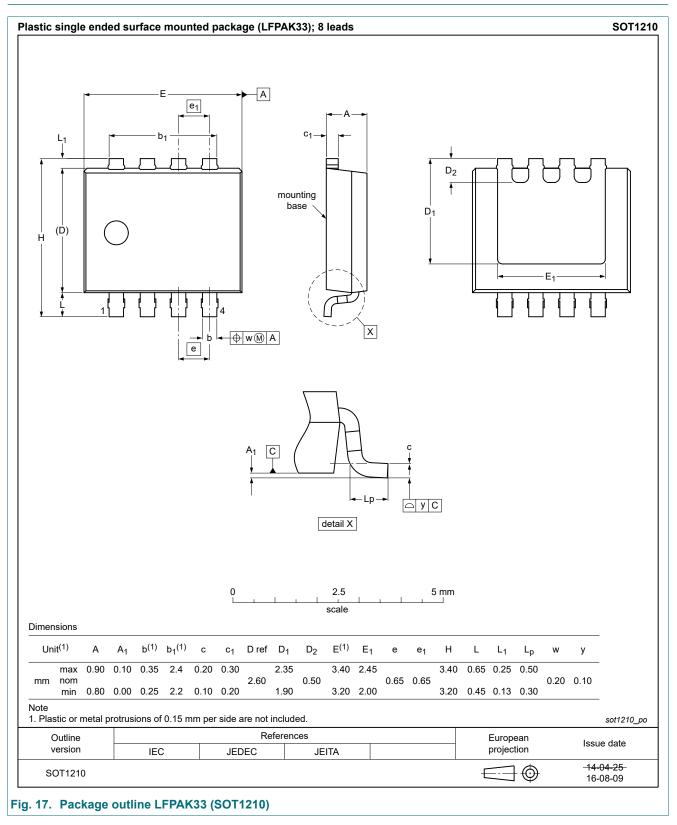


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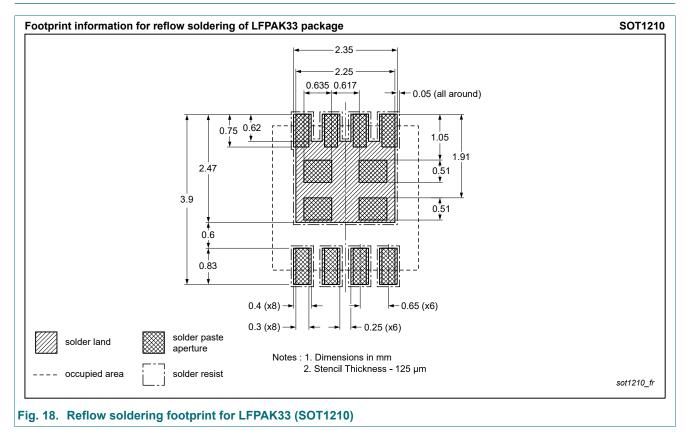


PSMN6R5-30MLD

11. Package outline



12. Soldering



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13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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